

# **ES3AB thru ES3MB**

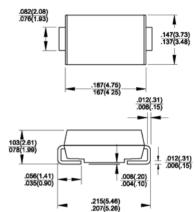
Super Fast Surface Mount Rectifiers Reverse Voltage 50 to 1000 Volts Forward Current 3.0 Amperes

#### **Features**

- Glass passivated chip
- ◆ Super fast switching for high efficiency
- ◆ For surface mounted applications
- ◆ Low forward voltage drop and high current capability
- ◆ Low reverse leakage current
- ◆ Plastic material has UL flammability classification 94V-0



### DO-214AA (SMB)



#### Dimensions in inches and (millimeters)

## **Mechanical Data**

◆ Case : Molded plastic

◆ Polarity : Color band denote cathode◆ Weight : 0.003 ounce, 0.093 gram

## **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	ES 3AB	ES 3BB	ES 3CB	ES 3DB	ES 3FB	ES 3GB	ES 3JB	ES 3KB	ES 3MB	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	600	800	1000	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	300	400	600	800	1000	Volts
Maximum average forward rectified current @T <sub>L</sub> =100°C	I <sub>(AV)</sub>	3.0								Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	100.0								Amps	
Maximum forward voltage @ 3.0A DC	V <sub>F</sub>	0.92				1.25		1.7		Volts	
Maximum DC reverse current @ T_=25°C at rated DC blocking voltage @ T_=125°C	I <sub>R</sub>	10.0 500								uA uA	
Maximum reverse recovery time (Note 1)	t <sub>rr</sub>	25									nS
Typical junction capacitance (Note 2)	C <sub>J</sub>	45									pF
Typical thermal resistance (Note 3) (Note 4)	R <sub>eJL</sub> R <sub>eJA</sub>	10 50									°C/W
Operating junction temperature range	T <sub>J</sub>	-55 to +150									°C
Storage temperature range	T <sub>stg</sub>	-55 to +150								°C	

Notes:

- 1. Reverse Recovery Test Conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Thermal Resistance junction to Lead.
- 4. Thermal Resistance junction to Ambient.

